

# Design Assignment 1

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Directory:

**1. COMPONENTS LIST AND CONNECTION BLOCK DIAGRAM w/ PINS**  
N/A

**2. INITIAL/MODIFIED/DEVELOPED CODE OF TASK 1/A**

Assembly Code for Task 1
--------------------------

```
. include <m328pdef.inc>
```

```
.def num1_H = R18 ; define upper byte of number 1 as r18  
.def num1_L = R19 ; define lower byte of number 1 as r19  
.def num2_H = R20 ; define upper byte of number 2 as r20  
.def num2_L = R21 ; define lower byte of number 2 as r21
```

```
.ORG 0 ; ROM starting at 0  
; task 1, store 16-bit number 0x1234 into the SRAM location 0x402  
LDI R16, 0x34 ; R16 = 0x34  
LDI XL, LOW(0x402) ; load the low byte of X with value 0x02  
LDI XH, HIGH(0x402) ; load the high byte of X with value 0x4  
ST X+, R16 ; copy R16 to memory location X  
LDI R16, 0x12 ; R16 = 0x12  
ST X+, R16 ; copy R16 to memory location X
```

```
; task 2, store 16-bit number 0x5678 into the SRAM location 0x410  
LDI R17, 0x56 ; R17 = 0x56  
LDI XL, LOW(0x410) ; load the low byte of X with value 0x10  
LDI XH, HIGH(0x410) ; load the high byte of X with value 0x4  
ST X+, R17 ; copy R17 to memory location X  
LDI R17, 0x78 ; R17 = 0x78  
ST X+, R17 ; copy R17 to memory location X
```

```
; task 3, need to add 0x1234 and 0x5678, then store into the EEPROM
```

```

LDI num1_L, 0x34      ; num1_L = 0x34
LDI num2_L, 0x56      ; num1_L = 0x56
LDI num1_H, 0x12      ; num1_H = 0x12
LDI num2_H, 0x78      ; num1_H = 0x78
ADD num1_L, num2_L    ; adding the lower bytes of number
ADC num1_H, num2_H    ; adding the upper bytes of number

LDI XH, HIGH(0x20)    ; load the high byte of X with value 0x0
LDI XL, LOW(0x20)     ; load the low byte of X with value 0x2
mov R22, num1_L
CALL STORE_IN_EEPROM ; call the label
LDI XH, HIGH(0x21)    ; load the high byte of X with value 0x1
LDI XL, LOW(0x21)     ; load the low byte of X with value 0x2
mov R22, num1_H
CALL STORE_IN_EEPROM ; call the label

; task 4, store 16-bit numbers into 0x0910 then retrieve to 0x500 SRAM and add the 10 ;
; number, store it to 0x406
LDI R25, 0x00        ; R25 = 0x00
LDI num10, 0xA       ; num10 = 0xA
LDI XL, LOW(0x500)    ; load the low byte of X with value 0x00
LDI XH, HIGH(0x500)   ; load the high byte of X with value 0x5
LDI ZH, HIGH(XSQR_TABLE<<1) ; look-up table high-byte adder
LDI ZL, LOW(XSQR_TABLE<<1) ; look-up table low-byte adder
L1:

```

```

; part of task 3
STORE_IN_EEPROM:

```

```

; part of task 4
.ORG 0x0910
XSQR_TABLE:

```

### 3. DEVELOPED MODIFIED CODE OF TASK 2/A from TASK 1/A

Assembly Code for Task 1
--------------------------

```

. include <m328pdef.inc>

```

```
. set EEMWE = EEMPE
. set EEWE = EEPE
. EQU SUM = 0x406
```

```
.def num1_H = R18 ; define upper byte of number 1 as r18
.def num1_L = R19 ; define lower byte of number 1 as r19
.def num2_H = R20 ; define upper byte of number 2 as r20
.def num2_L = R21 ; define lower byte of number 2 as r21
.def num10 = R23 ; define number of times the number will be add as r23
```

```
.ORG 0 ; ROM starting at 0
```

```
; part of task 3
```

```
LDI R22, HIGH(RAMEND)
OUT SPH, R22
LDI R22, LOW(RAMEND)
OUT SPL, R22
```

```
; task 1, store 16-bit number 0x1234 into the SRAM location 0x402
```

```
LDI R16, 0x34 ; R16 = 0x34
LDI XL, LOW(0x402) ; load the low byte of X with value 0x02
LDI XH, HIGH(0x402) ; load the high byte of X with value 0x4
ST X+, R16 ; copy R16 to memory location X
LDI R16, 0x12 ; R16 = 0x12
ST X+, R16 ; copy R16 to memory location X
```

```
; task 2, store 16-bit number 0x5678 into the SRAM location 0x410
```

```
LDI R17, 0x56 ; R17 = 0x56
LDI XL, LOW(0x410) ; load the low byte of X with value 0x10
LDI XH, HIGH(0x410) ; load the high byte of X with value 0x4
ST X+, R17 ; copy R17 to memory location X
LDI R17, 0x78 ; R17 = 0x78
ST X+, R17 ; copy R17 to memory location X
```

```
; task 3, need to add 0x1234 and 0x5678, then store into the EEPROM
```

```
LDI num1_L, 0x34 ; num1_L = 0x34
LDI num2_L, 0x56 ; num1_L = 0x56
LDI num1_H, 0x12 ; num1_H = 0x12
LDI num2_H, 0x78 ; num1_H = 0x78
ADD num1_L, num2_L ; adding the lower bytes of number
ADC num1_H, num2_H ; adding the upper bytes of number
```

```
LDI XH, HIGH(0x20) ; load the high byte of X with value 0x0
LDI XL, LOW(0x20) ; load the low byte of X with value 0x2
mov R22, num1_L
CALL STORE_IN_EEPROM ; call the label
```

```

LDI XH, HIGH(0x21)           ; load the high byte of X with value 0x1
LDI XL, LOW(0x21)            ; load the low byte of X with value 0x2
mov R22, num1_H
CALL STORE_IN_EEPROM         ; call the label

; task 4, store 16-bit numbers into 0x0910 then retrieve to 0x500 SRAM and add the 10 ;
; number, store it to 0x406
LDI R25,0x00                 ; R25 =0x00
LDI num10,0xA                ; num10 = 0xA
LDI XL, LOW(0x500)           ; load the low byte of X with value 0x00
LDI XH, HIGH(0x500)         ; load the high byte of X with value 0x5
LDI ZH, HIGH(XSQR_TABLE<<1) ; look-up table high-byte adder
LDI ZL, LOW(XSQR_TABLE<<1)  ; look-up table low-byte adder
L1: LPM R24, Z+               ; read the table, then increment Z
    ST X+, R24                ; store R24 in RAM and increment X
    ADD R25, R24              ; add 24 to r25
    dec num10                 ; decrement num10 by 1
    BRNE L1                   ; check if num10! = 0, then jump to L1
    STS SUM, R25              ; save the sum of r25 in location 0x406

```

```

HERE:
RJMP HERE

```

```

; part of task 3
STORE_IN_EEPROM:
SBIC EECR, EEPE
RJMP STORE_IN_EEPROM
OUT EEARH, XH
OUT EEARL, XL
OUT EEDR, R22
SBI EECR, EEMPE
SBI EECR, EEPE
RET

```

```

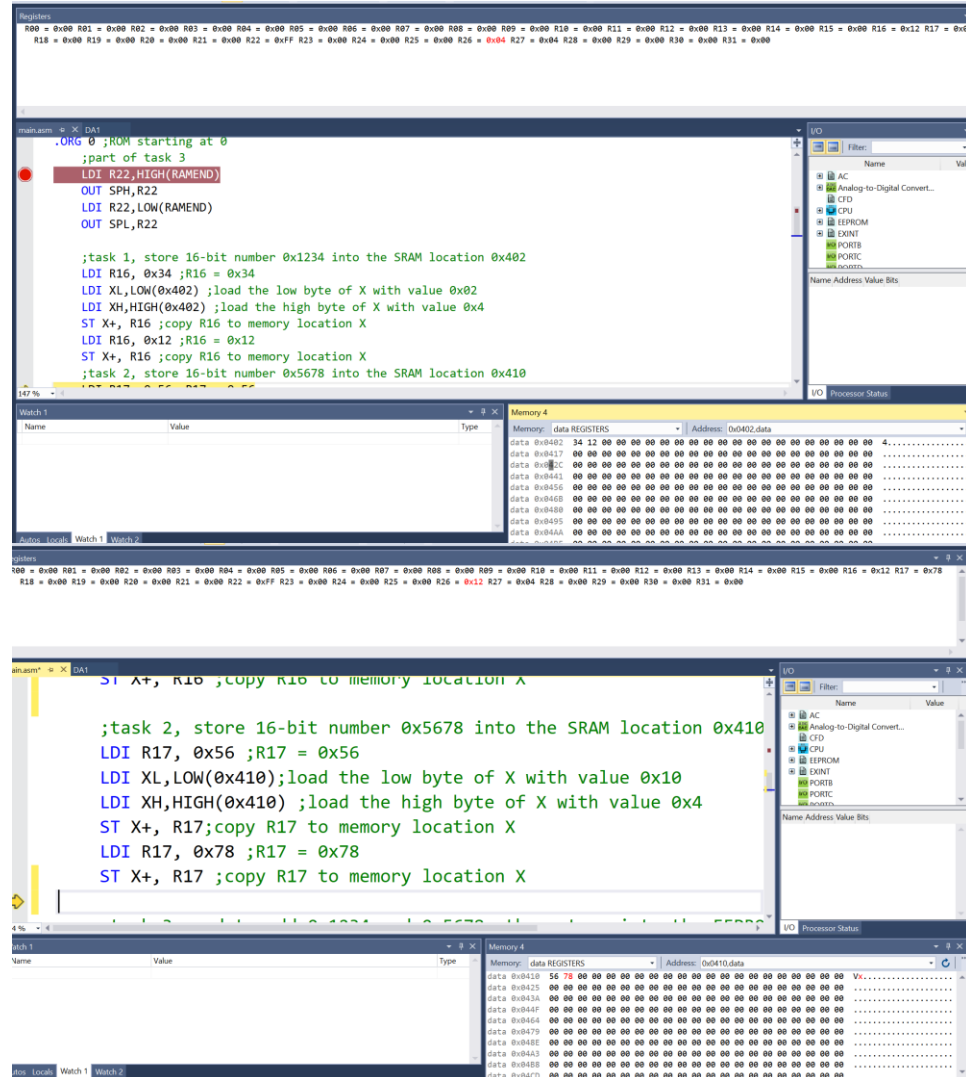
; part of task 4
.ORG 0x0910
XSQR_TABLE:
.DB 0,2,6,9,13,15,21,25,30,36

```

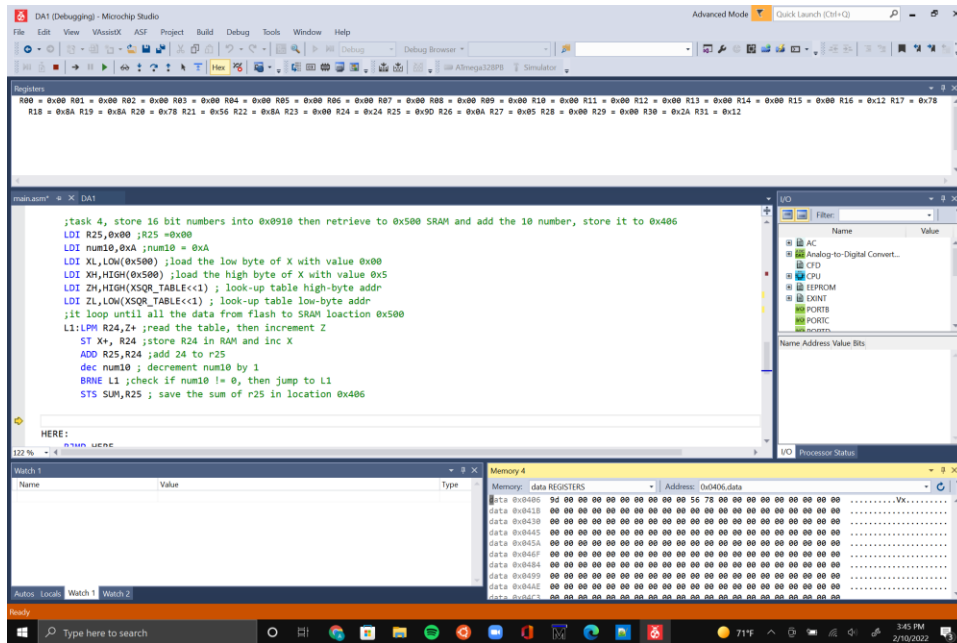
## 4. SCHEMATICS

N/A

## 5. SCREENSHOTS OF EACH TASK OUTPUT (ATMEL STUDIO OUTPUT)







## 6. SCREENSHOT OF EACH DEMO (BOARD SETUP)

N/A

## 7. VIDEO LINKS OF EACH DEMO

N/A

## 8. GITHUB LINK OF THIS DA

[https://github.com/AngeloNol/DA\\_submission.git](https://github.com/AngeloNol/DA_submission.git)